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April 2015

FGA6560WDF 650 V, 60 A Field Stop Trench IGBT

Features

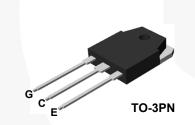
- Maximum Junction Temperature : T_J =175^oC
- Positive Temperaure Co-efficient for Easy Parallel Operating
- High Current Capability
- Low Saturation Voltage: V_{CE(sat)} =1.8 V(Typ.) @ I_C = 60 A
- 100% of the Parts Tested for $I_{LM}(1)$
- High Input Impedance
- · Fast Switching
- RoHS Compliant

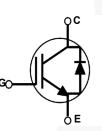
General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 3rd generation IGBTs offer the optimum performance for welder and industrial applications where low conduction and switching losses are essential.

Applications

- Welder and Industrial Application
- Power Factor Correction





Absolute Maximum Ratings

Symbol	Description		FGA6560WDF	Unit	
V _{CES}	Collector to Emitter Voltage		650	V	
V _{GES}	Gate to Emitter Voltage		± 20	V	
	Transient Gate to Emitter Voltage		± 30	V	
I _C	Collector Current	@ T _C = 25 ^o C	120	А	
'C	Collector Current	@ T _C = 100°C	60	А	
I _{LM (1)}	Pulsed Collector Current	@ T _C = 25 ^o C	180	А	
I _{CM (2)}	Pulsed Collector Current		180	А	
I _F	Diode Forward Current	@ T _C = 25°C	60	А	
	Diode Forward Current	@ T _C = 100°C	30	А	
I _{FM (2)}	Pulsed Diode Maximum Forward Curren	120	А		
P _D	Maximum Power Dissipation	@ T _C = 25°C	306	W	
. D	Maximum Power Dissipation	n Power Dissipation $@T_C = 100^{\circ}C$		W	
TJ	Operating Junction Temperature		-55 to +175	°C	
T _{stg}	Storage Temperature Range		-55 to +175	°C	
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C	

Notes:

1. V_{CC} = 400 V, V_{GE} = 15 V, I_C =180 A, R_G = 62 $\Omega,$ Inductive Load

2. Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	FGA6560WDF	Unit	
R _{0JC} (IGBT)	Thermal Resistance, Junction to Case, Max.	0.49	°C/W	
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case, Max.	1.75	°C/W	
R _{θJA}	Thermal Resistance, Junction to Ambient, Max.	40	°C/W	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FGA6560WDF	FGA6560WDF	TO-3PN	Tube	-	-	30

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

Symbol	Parameter	er Test Conditions		Тур.	Max.	Unit
Off Charac	teristics					
BV _{CES} Collector to Emitter Breakdown Voltage		V _{GE} = 0V, I _C = 1 mA	650	-	-	V
ΔBV _{CES} / ΔT _J	Temperature Coefficient of Breakdown Voltage	$I_{\rm C}$ = 1 mA, Reference to 25°C	-	0.6	-	V/ºC
I _{CES}	Collector Cut-Off Current	-	-	250	μA	
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0 V$	-	-	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	I_{C} = 60 mA, V_{CE} = V_{GE}	4.1	5.6	7.6	V
()		I _C = 60 A, V _{GE} = 15 V	-	1.8	2.3	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	$I_{C} = 60 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 175^{\circ}\text{C}$	-	2.3	-	V
Dynamic C	characteristics					
C _{ies}	Input Capacitance		-	2419	-	pF
C _{oes}	Output Capacitance	V _{CE} = 30 V, V _{GE} = 0 V,	-	82	-	pF
C _{res}	Reverse Transfer Capacitance	f = 1MHz	-	31	-	pF
	Characteristics				<u> </u>	
t _{d(on)}	Turn-On Delay Time		Γ-	25.6	-	ns
t _r	Rise Time	-	-	67.2	-	ns
t _{d(off)}	Turn-Off Delay Time	V _{CC} = 400 V, I _C = 60 A,	-	71	-	ns
t _f	Fall Time	R _G = 6 Ω, V _{GE} = 15 V,	-	22	-	ns
Eon	Turn-On Switching Loss	Inductive Load, $T_C = 25^{\circ}C$	-	2.46	-	mJ
E _{off}	Turn-Off Switching Loss	1	-	0.52	-	ml
						mJ
E _{ts}	Total Switching Loss		-	2.98	-	mJ
E _{ts}	Total Switching Loss Turn-On Delay Time	-	-	2.98 22.4	-	_
E _{ts} t _{d(on)}		-			-	mJ
E _{ts} t _{d(on)} t _r	Turn-On Delay Time	- - - V _{CC} = 400 V, I _C = 60 A,	-	22.4	-	mJ ns
E _{ts} t _{d(on)} t _r t _{d(off)}	Turn-On Delay Time Rise Time	$R_{G} = 6 \Omega, V_{GF} = 15 V,$	-	22.4 63.2	-	mJ ns ns
E _{ts} t _{d(on)} t _r t _{d(off)} t _f	Turn-On Delay Time Rise Time Turn-Off Delay Time		- ·	22.4 63.2 77	-	mJ ns ns ns
-	Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time	$R_{G} = 6 \Omega, V_{GF} = 15 V,$	· ·	22.4 63.2 77 22		mJ ns ns ns ns

Electrical Characteristics of the IGBT (Continued)

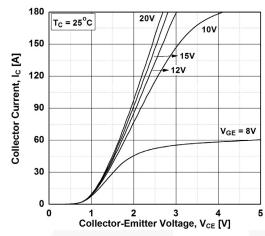
Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
Qg	Total Gate Charge	V _{CE} = 400 V, I _C = 60 A, V _{GE} = 15 V	-	84	-	nC
Q _{ge}	Gate to Emitter Charge		-	15	-	nC
Q _{gc}	Gate to Collector Charge		-	32	-	nC

Electrical Characteristics of the Diode T_C = 25°C unless otherwise noted

Symbol	Parameter		Test Conditions			Min.	Тур.	Мах	Unit
V _{FM}	Diode Forward Voltage	I _F =	30 A		T _C = 25°C	-	1.8	2.3	V
					T _C = 175 ^o C	-	1.7	-	
E _{rec}	Reverse Recovery Energy				T _C = 175 ^o C	-	233	-	uJ
t _{rr}	Diode Reverse Recovery Time	I _F =	30 A (1 = /01 = 200 A/05)		T _C = 25°C	-	110	-	ns
					T _C = 175 ^o C	-	271	-	
Q _{rr}	Diode Reverse Recovery Charge				T _C = 25 ^o C	-	400	-	nC
					T _C = 175 ^o C	-	1740	-	

Typical Performance Characteristics







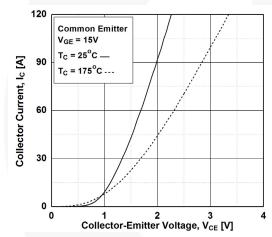
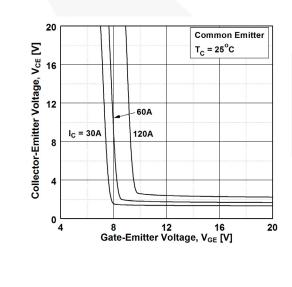
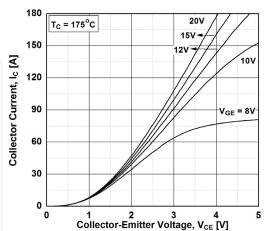


Figure 5. Saturation Voltage vs. V_{GE}



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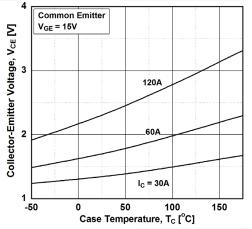
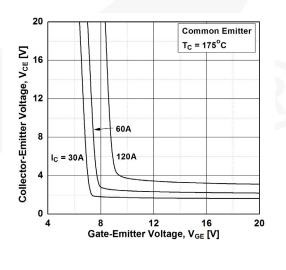
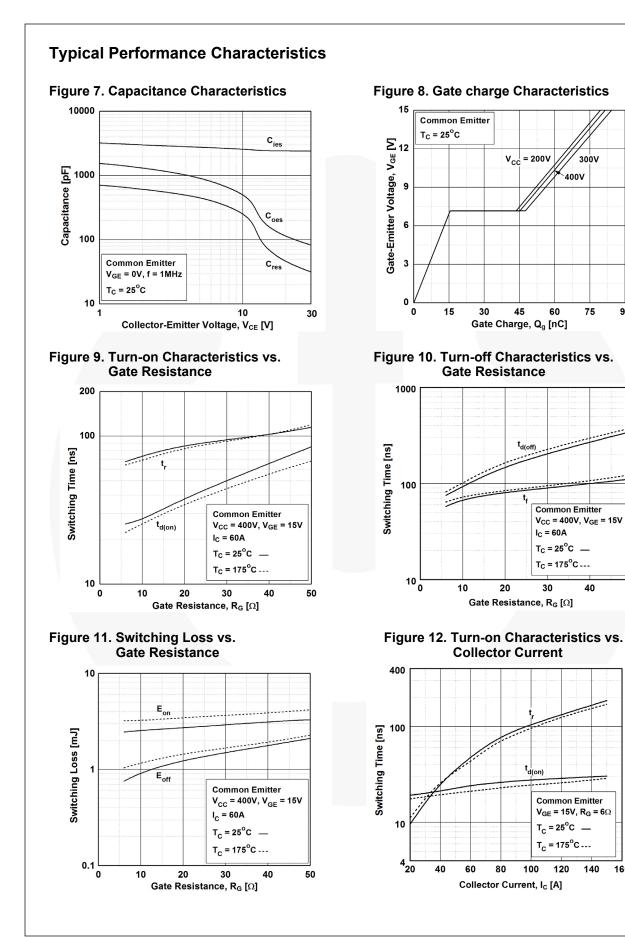


Figure 6. Saturation Voltage vs. V_{GE}



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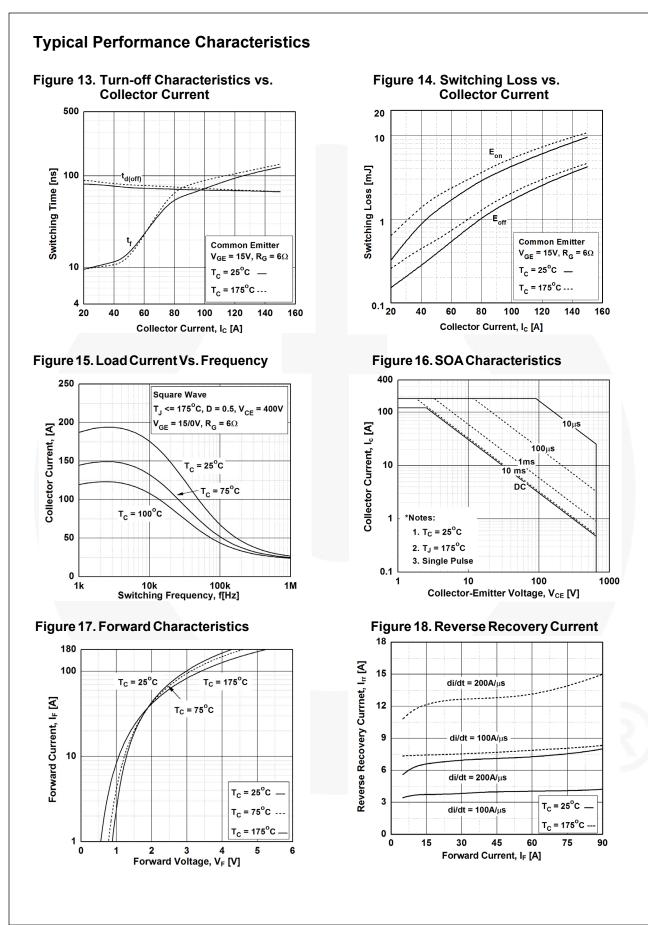
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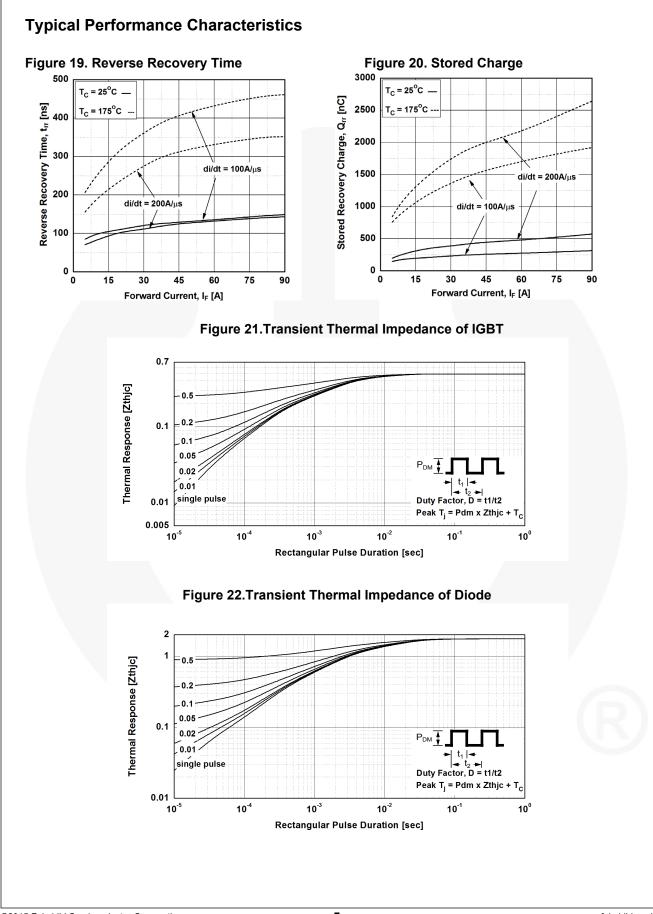
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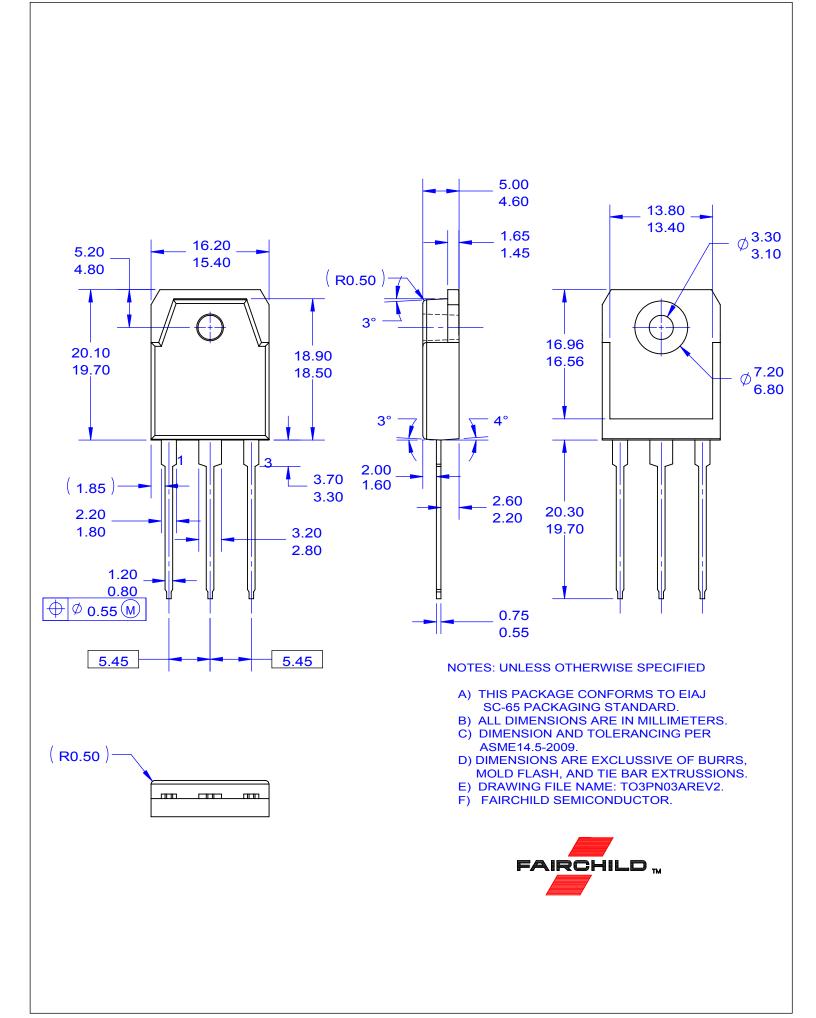
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